

# **HAT2202C**

# Silicon N Channel MOS FET Power Switching

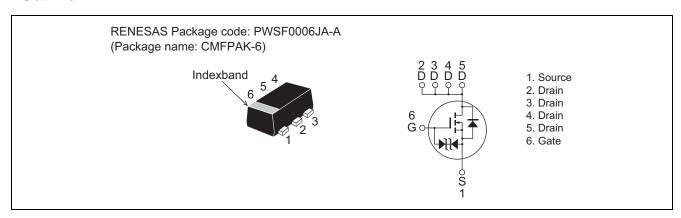
R07DS1179EJ0700 (Previous: REJ03G1236-0600)

> Rev.7.00 Mar 19, 2014

#### **Features**

- Low on-resistance  $R_{DS(on)} = 31 \text{ m}\Omega \text{ typ. (at } V_{GS} = 4.5 \text{ V})$
- Low drive current.
- High density mounting
- 2.5 V gate drive devices.

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	20	V
Gate to source voltage	$V_{GSS}$	±12	V
Drain current	I <sub>D</sub>	3	Α
Drain peak current	I <sub>D(pulse)</sub> Note1	12	Α
Body - Drain diode reverse drain current	I <sub>DR</sub>	3	А
Channel dissipation	Pch <sup>Note 2</sup>	900	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. When using the glass epoxy board. (FR4  $40 \times 40 \times 1.6$  mm)

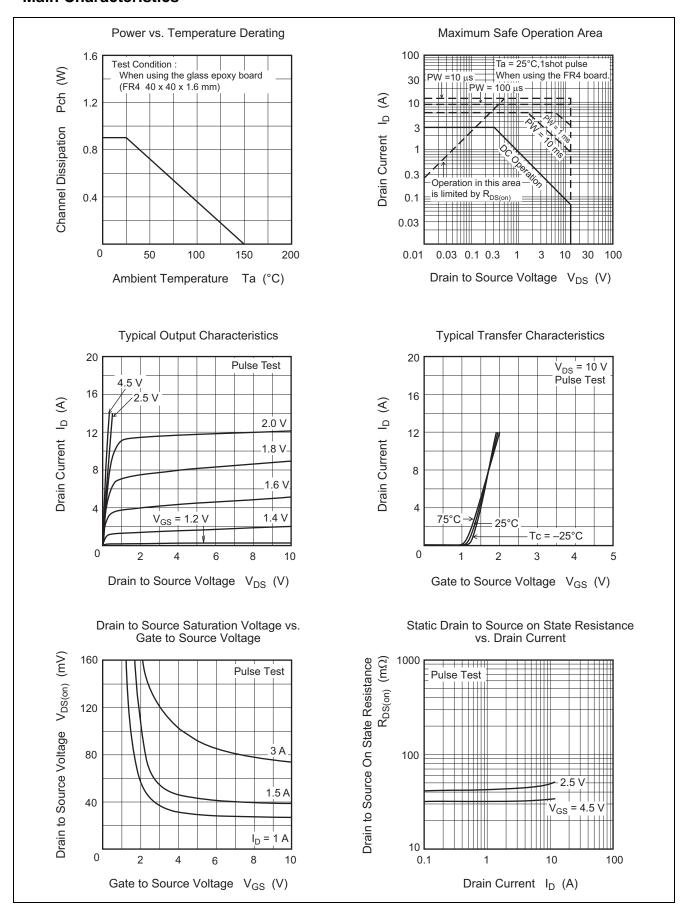
# **Electrical Characteristics**

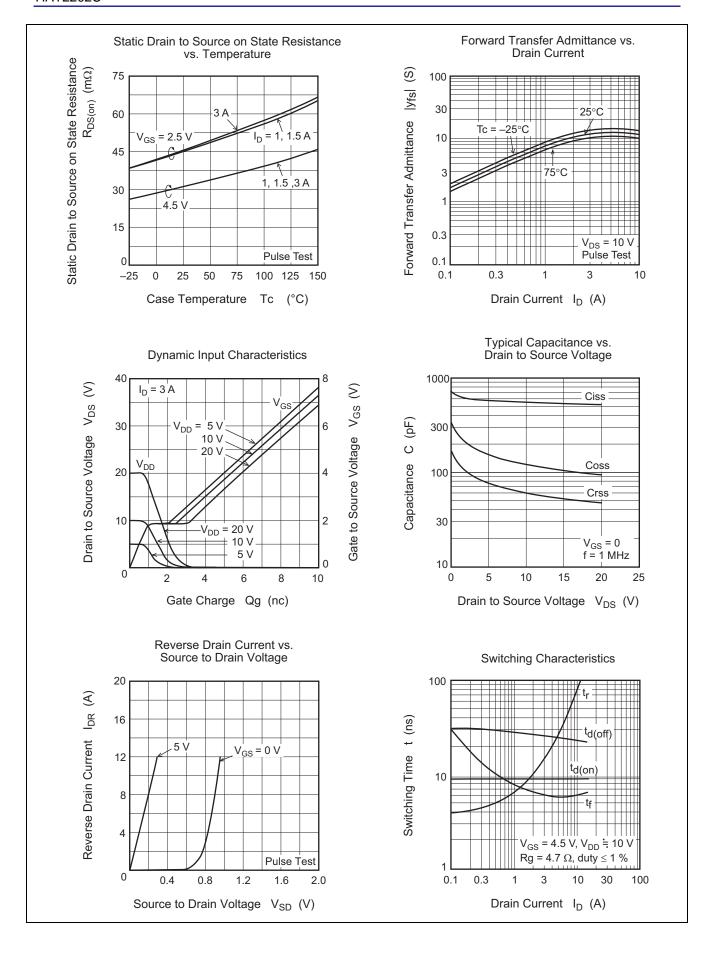
 $(Ta = 25^{\circ}C)$ 

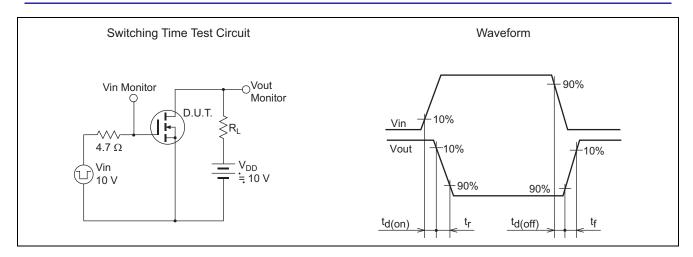
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	20	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to Source breakdown voltage	$V_{(BR)GSS}$	±12	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to Source leakage current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 10V, V_{DS} = 0$
Drain to Source leakage current	I <sub>DSS</sub>		_	1	μΑ	$V_{DS} = 20 \text{ V}, V_{GS} = 0$
Gate to Source cutoff voltage	$V_{GS(th)}$	0.4	_	1.4	V	$I_D = 10 \text{ V}, I_D = 1 \text{ mA}$
Drain to Source on state resistance	R <sub>DS(on)</sub>		31	40	mΩ	$I_D = 1.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note3}}$
	R <sub>DS(on)</sub>		43	55	mΩ	$I_D = 1.5 \text{ A}, V_{GS} = 2.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	y <sub>fs</sub>	6.5	9.5		S	$I_D = 1.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note3}}$
Input capacitance	Ciss		520		pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	115		pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	60	_	pF	
Total gate charge	Qg	_	6	_	nC	$V_{DD} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$
Gate to Source charge	Qgs	_	1	_	nC	I <sub>D</sub> = 3 A
Gate to Drain charge	Qgd	_	1.4	_	nC	
Turn - on delay time	t <sub>d(on)</sub>	_	9	_	ns	$\begin{split} I_D &= 1.5 \text{ A}, \\ V_{GS} &= 10 \text{ V}, V_{DD} = 10 \text{ V}, \\ R_L &= 6.7  \Omega, R_g = 4.7  \Omega \end{split}$
Rise time	t <sub>r</sub>	_	8	_	ns	
Turn - off delay time	$t_{d(off)}$	_	28	_	ns	
Fall time	t <sub>f</sub>	_	6	_	ns	
Body - Drain diode forward voltage	$V_{DF}$		0.8	1.1	V	$I_F = 3 \text{ A}, V_{GS} = 0^{\text{Note3}}$

Notes: 3. Pulse test

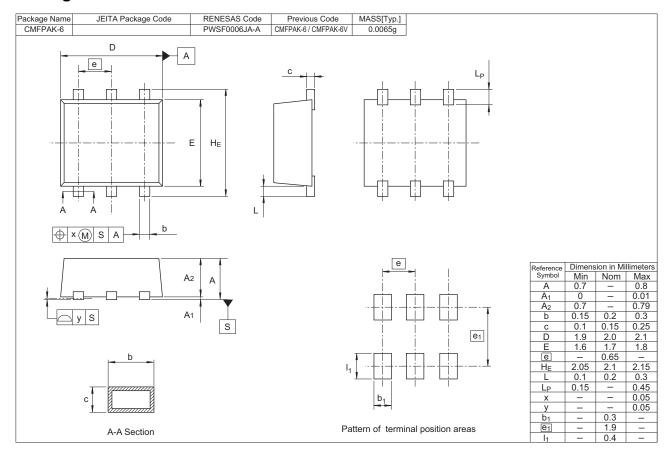
#### **Main Characteristics**







### **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
HAT2202C-EL-E	3000 pcs	Taping

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Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd. Room 1709, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100191, P.R.China Tei: +86-10-2035-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 161F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2856-5688, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei 105-Tel: +886-2-8175-9600, Fax: +886 2-8175-9670 . ipei 10543, Taiwan

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Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd. 12F., 234 Teheran-ro, Gangnam-Ku, Seoul, 135-920, Korea Tel: +82-2-558-3737, Fax: +82-2-558-5141